

HiPerFRED

V_{RRM} = 1200 V
 I_{FAV} = 2x 8 A
 t_{rr} = 40 ns

High Performance Fast Recovery Diode

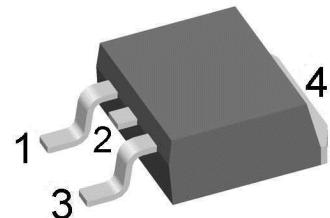
Low Loss and Soft Recovery

Common Cathode

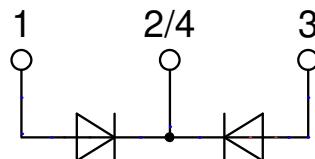
Part number

DSEC16-12AS

Marking on Product: DSEC16-12AS



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

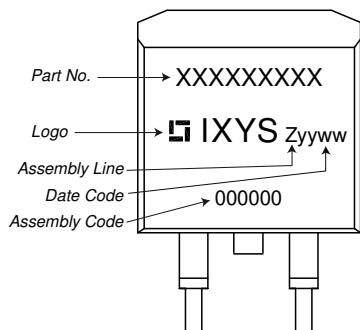
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Fast Diode

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1200	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1200	V
I_R	reverse current, drain current	$V_R = 1200 \text{ V}$ $V_R = 1200 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		60 0.25	μA mA
V_F	forward voltage drop	$I_F = 10 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		2.94	V
		$I_F = 20 \text{ A}$			3.57	V
		$I_F = 10 \text{ A}$	$T_{VJ} = 150^\circ\text{C}$		1.96	V
		$I_F = 20 \text{ A}$			2.56	V
I_{FAV}	average forward current	$T_C = 135^\circ\text{C}$ rectangular	$T_{VJ} = 175^\circ\text{C}$		8	A
V_{F0}	threshold voltage	$T_{VJ} = 175^\circ\text{C}$			1.20	V
r_F	slope resistance } for power loss calculation only				57	$\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				2.5	K/W
R_{thCH}	thermal resistance case to heatsink			0.25		K/W
P_{tot}	total power dissipation	$T_C = 25^\circ\text{C}$			60	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		40	A
C_J	junction capacitance	$V_R = 600 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		3	pF
I_{RM}	max. reverse recovery current	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$			4	A
t_{rr}	reverse recovery time		$T_{VJ} = 25^\circ\text{C}$		8	A
		$I_F = 10 \text{ A}; V_R = 600 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$		40	ns
			$T_{VJ} = 100^\circ\text{C}$		115	ns

Package TO-263 (D2Pak)

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			35	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
F_c	mounting force with clip		20		60	N

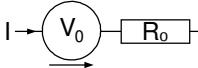
Product Marking


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEC16-12AS-TRL	DSEC16-12AS	Tape & Reel	800	507922
Alternative	DSEC16-12AS-TUB	DSEC16-12AS	Tube	50	507915

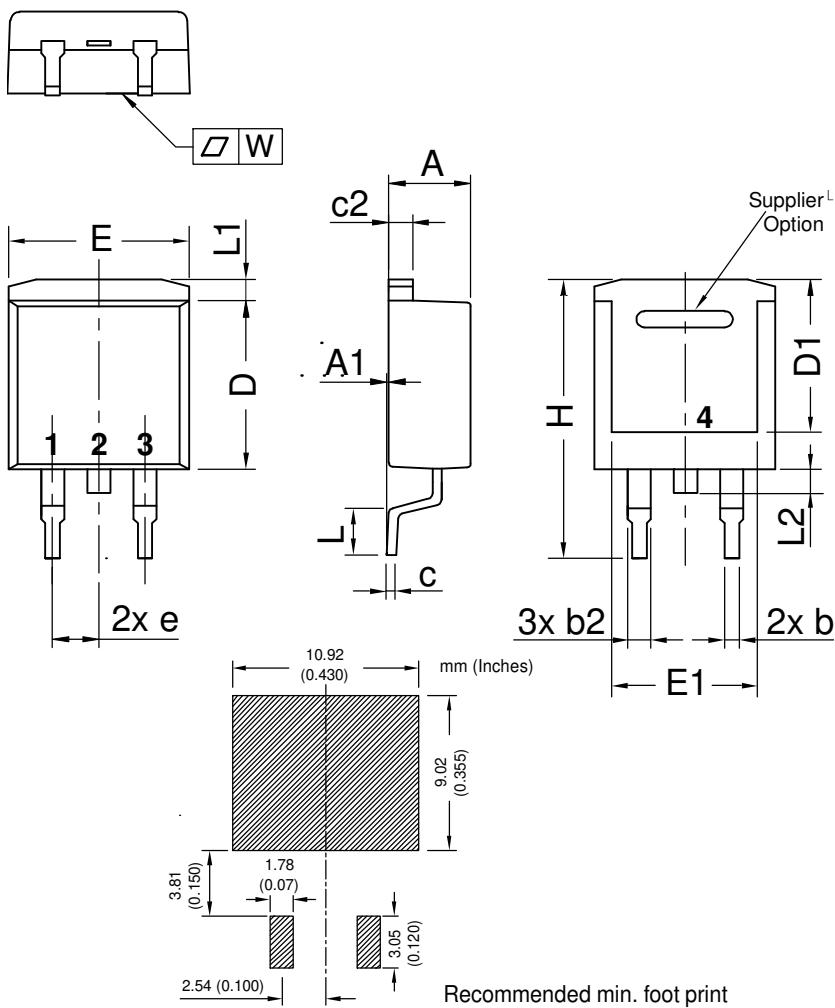
Similar Part	Package	Voltage class
DSEC16-12A	TO-220AB (3)	1200

Equivalent Circuits for Simulation
^{*}on die level

 $T_{VJ} = 175 \text{ }^{\circ}\text{C}$

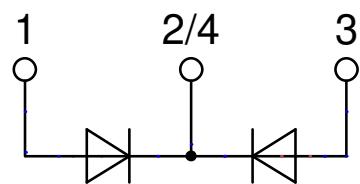
	Fast Diode
$V_{0\max}$	threshold voltage
$R_{0\max}$	slope resistance *

V
 $\text{m}\Omega$

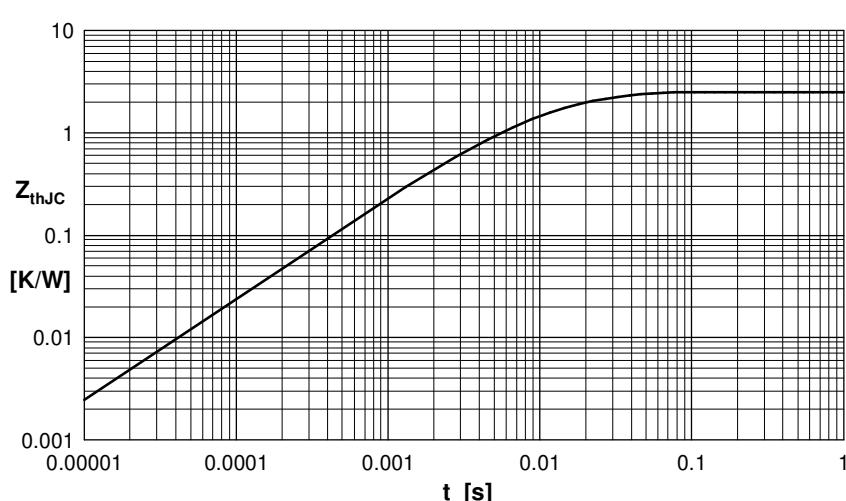
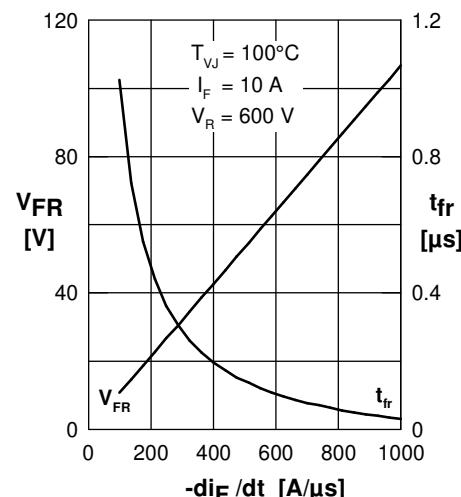
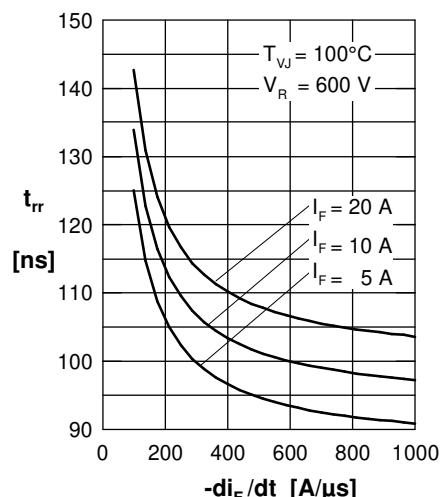
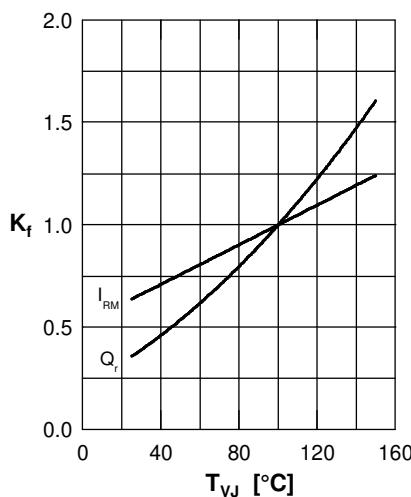
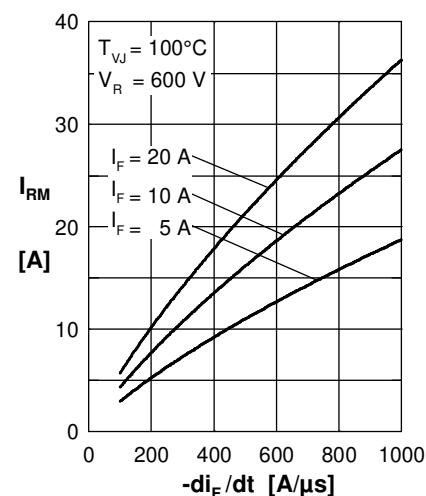
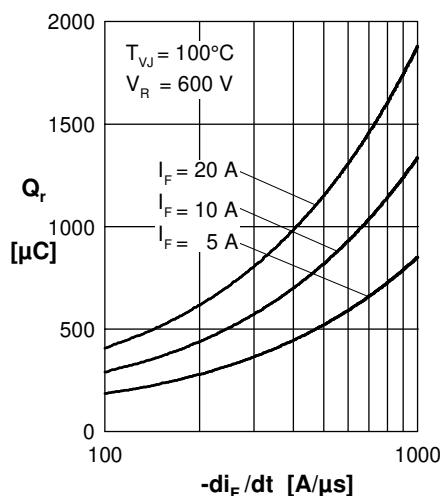
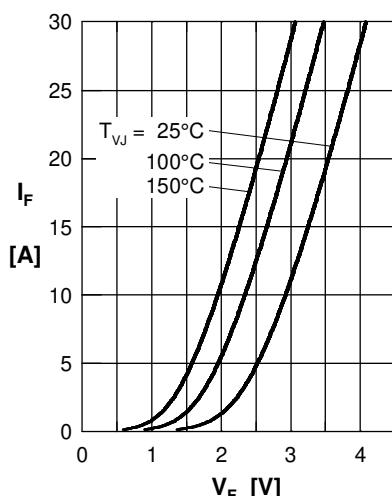
Outlines TO-263 (D2Pak)


Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2,54 BSC		0,100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

All dimensions conform with
and/or within JEDEC standard.



Fast Diode



Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0200	0.0002
2	0.3000	0.0040
3	0.8000	0.0200
4	1.3800	0.0100

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